## NSN 5962-01-400-2992

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View Online at https://aerobasegroup.com/nsn/5962-01-400-2992 **Body Length:** 0.358 inches **Body Width:** 0.075 inches **Body Height:** 0.358 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Nfra red sear e/i fscm 99971 **Features Provided:** Burn in and electrostatic sensitive and monolithic and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Leaded chip carrier **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Current Rating Per Characteristic:** 70.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.0 volts power source **Time Rating Per Chacteristic:** 20.00 nanoseconds input to output access **Memory Device Type:** Pal **Terminal Type And Quantity:** 20 gullwing Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** Yes - demil/mli

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